L Number	Hits	Search Text	DB	Time stamp
-	603	(345/82-83).CCLS.	USPAT;	2003/11/18 12:18
			EPO; JPO;	
			IBM TDB	
-	824	(345/76-81).CCLS.	USPAT;	2002/07/15 14:28
			EPO; JPO;	
			IBM TDB	
_	11911	(current or voltage) near5 color	USPĀT;	2002/07/15 14:40
		,	EPO; JPO;	
			IBM_TDB	
-	73	(((345/82-83).CCLS.) or ((345/76-81).CCLS.)) and ((current or voltage)	USPĀT;	2002/07/15 14:39
		near5 color)	EPO; JPO;	
		,	IBM TDB	
-	2	("3740570").PN.	USPĀT;	2002/07/15 14:32
			EPO; JPO;	
			IBM_TDB	
-	25994	(TFT or (thin adj film adj transistor))	USPĀT;	2003/11/18 10:12
			EPO; JPO;	
			IBM_TDB	1
-	113	((TFT or (thin adj film adj transistor))) same ((current or voltage) near5	USPAT;	2003/11/18 11:05
e		color)	EPO; JPO;	
		,	IBM TDB	
.	1	(((345/82-83).CCLS.) or ((345/76-81).CCLS.)) and (((TFT or (thin adj	USPAT;	2002/07/15 14:39
		film adj transistor))) same ((current or voltage) near5 color))	EPO; JPO;	2002/0//15 11:55
		((*************************************	IBM_TDB	
_	6107	((current or voltage near2 control)) near5 color	USPAT;	2002/07/15 14:46
		((*************************************	EPO; JPO;	2002/07/15 14:40
			IBM_TDB	
_	20	((TFT or (thin adj film adj transistor))) same (((current or voltage near2	USPAT;	2003/11/18 10:15
	_~	control)) near5 color)	EPO; JPO;	2003/11/16 10.13
		Controlly news colory	IBM_TDB	
_	715	((current or voltage) near2 control) near5 color	USPAT;	2002/07/15 14:48
	'15	(Controll of Vollage) hear 2 control) hear 3 color	EPO; JPO;	2002/07/13 14.48
			IBM TDB	
_	4	((TFT or (thin adj film adj transistor))) same (((current or voltage) near2	USPAT;	2002/07/15 14:48
	·	control) near5 color)	EPO; JPO;	2002/07/13 14.40
	•	connecty near colory	IBM_TDB	
_	2	jp-10039791-\$.did.	EPO; JPO;	2002/07/17 10:45
	_	jp 10057771 ¢.did.	DERWENT	2002/07/17 10.45
_	1	1998-184157.NRAN.	DERWENT	2002/07/17 10:46
_	896	(TFT or (thin adj film adj transistor)) near5 size	USPAT;	2002/07/17 10:40
	0,0	(11 1 of (unit au) train aug trainsistor)) fical 5 size	EPO; JPO;	2002/07/17 13:33
			IBM_TDB	
_	16	("W/L" or "W adj L") same ((TFT or (thin adj film adj transistor)) near5	USPAT;	2002/07/17 12:22
	10	(W/L of W adj L) same ((11-1 of (min adj finn adj transistor)) nears	EPO; JPO;	2002/07/17 13:33
		, s.c.,	IBM TDB	
_	2	JP-09236790-\$.did.	EPO; JPO;	2002/07/17 13:29
	_	,	DERWENT	2002/07/17 13.29
_	12497	("W/L" or ("W" adj "L"))	USPAT;	2002/07/17 13:34
l	.2.,/	(2 or (ii aaj 12))	EPO; JPO;	2002/07/17 13:34
			IBM_TDB	
.	16	("W/L" or ("W" adj "L")) same ((TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 12:24
ļ	10	near5 size)		2002/07/17 13:34
		11000 0120)	EPO; JPO; IBM TDB	}
	0	(("W/L" or ("W" adj "L")) same ((TFT or (thin adj film adj transistor))		2002/07/17 12:24
	. 0	near5 size) not (("W/L" or "W adj L") same ((TFT or (thin adj film adj	USPAT; EPO; JPO;	2002/07/17 13:34
		transistor)) near5 size))		
_	2	((TFT or (thin adj film adj transistor)) same (("W/L" or ("W" adj "L"))))	IBM_TDB	2002/07/17 12:25
	2	((Tr T of (tillif adj Tillif adj transistor)) same (("W/L" or ("W" adj "L")))) same color	USPAT;	2002/07/17 13:35
		Surio coloi	EPO; JPO;	
_	1	("4810060").PN.	IBM_TDB	2002/05/15 115
-	1	(4010000).FN.	USPAT;	2002/07/17 14:25
			EPO; JPO;	
_	6	("A60027A" "A6015A6" "A716402" "A720170" "A700170"	IBM_TDB	0000/05/15 11 5
	O	("4600274" "4601546" "4716403" "4728172" "4728175"	USPAT	2002/07/17 14:25
		"4761058").PN.		

-	15	4810060.URPN.	USPAT	2002/07/17 14:26
-	2	(TFT or (thin adj film adj transistor)) same (emission adj efficiency)	USPAT;	2002/07/18 09:24
			EPO; JPO;	
			IBM_TDB	
-	537	(TFT or (thin adj film adj transistor)) same (electroluminescence or "EL")	USPAT;	2004/05/25 10:17
]			EPO; JPO;	
İ			IBM_TDB	
-	129	(TFT or (thin adj film adj transistor)) same (electroluminescence)	USPAT;	2002/07/17 15:27
			EPO; JPO;	
			IBM_TDB	
-	20	(TFT or (thin adj film adj transistor)) same (electroluminescence adj	USPAT;	2002/07/17 15:35
		element)	EPO; JPO;	
			IBM_TDB	
-	3250	switching near3 (TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 15:37
			EPO; JPO;	
			IBM TDB	
-	2161	driving near3 (TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 15:38
			EPO; JPO;	
			IBM_TDB	
l <u>-</u>	230	(switching near3 (TFT or (thin adj film adj transistor))) same (driving	USPAT;	2002/07/17 15:37
		near3 (TFT or (thin adj film adj transistor)))	EPO; JPO;	2002/07/17 13.57
1		include (11 1 or (aim acq min acq maisistor)))	IBM TDB	
_	171	(switching near3 (TFT or (thin adj film adj transistor))) with (driving	USPAT;	2002/07/17 15:37
	1 ./.	near3 (TFT or (thin adj film adj transistor)))	EPO; JPO;	2002/07/17 13.37
		incais (11 1 of (unit auj transistor)))	IBM TDB	
_	401	switching adj (TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 15:38
-	401	switching adj (11-1 of (tillif adj film adj transistor))		2002/07/17 15:38
			EPO; JPO;	
	478	driving adi (TET or (thin adi film adi transiator))	IBM_TDB	2002/07/17 15:20
-	4/6	driving adj (TFT or (thin adj film adj transistor))	USPAT;	2002/07/17 15:38
			EPO; JPO;	
	17	(and a big = -1; (TCT = -(abig = 4; Close 4; Annual at 2))	IBM_TDB	2002/05/15 15 20
-	17	(switching adj (TFT or (thin adj film adj transistor))) same (driving adj	USPAT;	2002/07/17 15:38
		(TFT or (thin adj film adj transistor)))	EPO; JPO;	
1	26020	(TET as (41: - 4: 61 4: 4	IBM_TDB	2002/07/10 00 22
-	26028	(TFT or (thin adj film adj transistor))	USPAT;	2002/07/18 09:23
			EPO; JPO;	
	62	(/TET (4Lin - 1: 61 1: 4 1: 4 1: 66 : 1	IBM_TDB	2002/05/10 00 54
-	62	((TFT or (thin adj film adj transistor))) and (emission adj efficiency)	USPAT;	2002/07/18 09:24
1			EPO; JPO;	
	214		IBM_TDB	
-	214	((TFT or (thin adj film adj transistor))) and (chromaticity)	USPAT;	2002/07/18 09:25
			EPO; JPO;	
		(//TPPP // 12 12 C1 12	IBM_TDB	
-	3	(((TFT or (thin adj film adj transistor))) and (emission adj efficiency))	USPAT;	2002/07/18 09:25
		and (((TFT or (thin adj film adj transistor))) and (chromaticity))	EPO; JPO;	
!		(11555000001111500420511) 723	IBM_TDB	
-	2	("5550066" "5684365").PN.	USPAT	2002/07/18 09:29
-	2	("6204610").PN.	USPAT;	2002/07/18 10:24
		2000 (5120(2)P.12)	DERWENT	
-	1	2000-651206.NRAN.	DERWENT	2002/07/18 10:25
-	1	("5684365").PN.	USPAT;	2002/07/18 10:57
			EPO; JPO;	
			IBM_TDB	
-	1	("6072272").PN.	USPAT;	2002/07/18 12:02
l			EPO; JPO;	
			IBM_TDB	
-	8	("4193015" "4220892" "5045750" "5311337" "5317437"	USPAT	2002/07/18 11:49
		"5467422" "5565754" "5654729").PN.		
-	0	6072272.URPN.	USPAT	2002/07/18 11:50
-	2	("6366025").PN.	USPAT;	2002/07/18 12:02
}			EPO; JPO;	
			DERWENT	
-	1	2001-082367.NRAN.	DERWENT	2002/07/18 12:02
-	1	2001-082367.NRAN.	DERWENT	2002/07/18 12:04
	1	2001-082367.NRAN.	DERWENT	2002/07/18 12:05

-	1	("6072272").PN.	USPAT;	2002/07/18 15:04
			EPO; JPO;	
		(MC14174CM) 773	IBM_TDB	
-	1	("6121726").PN.	USPAT;	2002/07/18 15:04
			EPO; JPO;	
		' 11#3000 # 1'1	IBM_TDB	0000/04/05 10 07
•	0	jp-1173928-\$.did.	USPAT;	2003/04/07 13:06
· - -			US-PGPUB;	
			EPO; JPO;	
		'. 1173000 A 1'1	IBM_TDB	
-	0	jp-1173928-\$.did.	EPO; JPO;	2003/04/07 13:06
	2	jp-01173928-\$.did.	DERWENT	2002/04/07 12:12
•		jp=011/3926-\$.uiu.	EPO; JPO; DERWENT	2003/04/07 13:12
	0	jp-001173928-\$.did.		2003/04/07 13:07
-		jp-001173926-3.uid.	EPO; JPO; DERWENT	2003/04/07 13:07
_	1	("6204610").PN.	USPAT;	2003/04/07 13:12
_	1	(0204010).114.	US-PGPUB;	2003/04/07 13:12
			EPO; JPO;	
			IBM_TDB	
	2	("6204610").PN.	USPAT;	2003/04/07 13:12
		(Section from	DERWENT	2003/07/07 13.12
_	1	2000-651206.NRAN.	DERWENT	2003/04/07 13:13
-	i	("5134253").PN.	USPAT;	2003/04/07 15:15
		(****	EPO; JPO;	2003/01/05 15:10
			IBM_TDB	
-	1	("4587378").PN.	USPAT;	2003/04/08 15:16
			EPO; JPO;	2003/01/00 13:10
			IBM_TDB	•
-	1	("4645869").PN.	USPAT;	2003/04/08 15:17
			EPO; JPO;	200010110012111
			IBM_TDB	
-	1	("4818827").PN.	USPĀT;	2003/04/08 15:17
		. ,	EPO; JPO;	
			IBM_TDB	
-	1	("4897511").PN.	USPAT;	2003/04/08 15:17
			EPO; JPO;	
	•		IBM_TDB	
-	1	("5159159").PN.	USPAT;	2003/04/08 15:18
			EPO; JPO;	
		(115,500,001) 79.5	IBM_TDB	
•	1	("5530209").PN.	USPAT;	2003/04/08 15:18
			EPO; JPO;	
	,	(#55/2201#\ DNI	IBM_TDB	,
-	1	("5563381").PN.	USPAT;	2003/04/08 15:18
]		EPO; JPO;	
_	1	("5077401") DN	IBM_TDB	2002/04/00 15 10
-	1	("5977491").PN.	USPAT;	2003/04/08 15:19
			EPO; JPO;	
_	1	("6239790").PN.	IBM_TDB USPAT;	2002/04/09 15:10
	'	(0=07.70).111.	EPO; JPO;	2003/04/08 15:19
			IBM TDB	
-	1	("6259491").PN.	USPAT;	2003/04/08 15:20
	[-	(EPO; JPO;	2003/04/08 13.20
			IBM_TDB	
-	1	("6304251").PN.	USPAT;	2003/04/08 15:20
]	`	EPO; JPO;	2005/04/00 15.20
	1		IBM_TDB	
-	1	("4625075").PN.	USPAT;	2003/04/08 15:20
			EPO; JPO;	111.505.15.20
]		IBM TDB	
-	1	("4001677").PN.	USPAT;	2003/04/08 15:44
			EPO; JPO;	
			IBM_TDB	

-	7	("5742129" "5745085" "5828181" "5886474" "5990629" "6028573" "6084579").PN.	USPAT	2003/04/17 11:25
-	4	TFT-EL same TFT-LCD	USPAT;	2003/11/18 10:10
			US-PGPUB;	
1	ļ		EPO; JPO;	
			IBM_TDB	
-	29624	(TFT or (thin adj film adj transistor))	USPAT;	2003/11/18 10:29
			EPO; JPO;	
l _	652	((TFT or (thin adj film adj transistor))) with (EL or electrolumisc\$5)	IBM_TDB USPAT;	2003/11/18 11:07
]	((11 1 of (unit adj transistor))) with (EE of electrotumises)	EPO; JPO;	2003/11/16 11.07
	1		IBM TDB	
-	10231	((TFT or (thin adj film adj transistor))) with (LCD or (liquid adj crystal	USPAT:	2003/11/18 10:30
		adj (diode or display)))	EPO; JPO;	
1			IBM_TDB	
-	143	(((TFT or (thin adj film adj transistor))) with (EL or electrolumisc\$5))	USPAT;	2003/11/18 10:14
	ļ	same (((TFT or (thin adj film adj transistor))) with (LCD or (liquid adj	US-PGPUB;	
		crystal adj (diode or display))))	EPO; JPO;	
	80	(((/TET on (thin odi film odi francistan))) with (EL on alestan))	IBM_TDB	2002/11/10 11 06
	00	((((TFT or (thin adj film adj transistor))) with (EL or electrolumisc\$5)) same (((TFT or (thin adj film adj transistor))) with (LCD or (liquid adj	USPAT; EPO; JPO;	2003/11/18 11:06
		crystal adj (diode or display)))) and @ad<19991004	IBM_TDB	
-	22346	(TFT or (thin adj film adj transistor))	USOCR	2003/11/18 10:32
-	1	(((TFT or (thin adj film adj transistor))) with (EL or electrolumisc\$5))	USOCR	2003/11/18 10:31
		and (((TFT or (thin adj film adj transistor))) with (LCD or (liquid adj		
		crystal adj (diode or display))))		
-	4	((USOCR	2003/11/18 10:31
		adj (diode or display)))		
-	1743	((TFT or (thin adj film adj transistor))) with (EL or electrolumisc\$5)	USOCR	2003/11/18 10:33
-	144	((TFT or (thin adj film adj transistor))) same ((current or voltage) near5	USPAT;	2003/11/18 11:05
		color)	EPO; JPO;	
_	105	(((TFT or (thin adj film adj transistor))) same ((current or voltage) near5	IBM_TDB USPAT;	2003/11/18 11:07
	103	color)) and @ad<19991004	EPO; JPO;	2003/11/16 11.0/
		,,	IBM TDB	
-	652	((TFT or (thin adj film adj transistor))) with (EL or electrolumisc\$5)	USPAT;	2003/11/18 11:08
			EPO; JPO;	
			IBM_TDB	
-	6	(((TFT or (thin adj film adj transistor))) same ((current or voltage) near5	USPAT;	2003/11/18 11:08
		color)) and (((TFT or (thin adj film adj transistor)))) with (EL or	EPO; JPO;	
_	0	electrolumisc\$5)) ((((TFT or (thin adj film adj transistor))) same ((current or voltage) near5	IBM_TDB	2002/11/10 11 00
	"	color) and (((TFT or (thin adj film adj transistor))) with (EL or	USPAT; EPO; JPO;	2003/11/18 11:08
		electrolumisc\$5))) and @ad<19991004	IBM_TDB	
-	54456	(EL or electrolumisc\$5)	USPAT;	2003/11/18 11:08
		,	EPO; JPO;	
			IBM_TDB	
-	12	(((TFT or (thin adj film adj transistor)))) same ((current or voltage) near5	USPAT;	2003/11/18 11:08
		color)) and ((EL or electrolumisc\$5))	EPO; JPO;	
	4	((((TET or (thin adi film adi transistan))) some ((IBM_TDB	2004/05/25 10 15
_	4	((((TFT or (thin adj film adj transistor))) same ((current or voltage) near5 color)) and ((EL or electrolumisc\$5))) and @ad<19991004	USPAT;	2004/05/25 10:43
		wau\13331004	EPO; JPO; IBM TDB	
-	1	("4810060").PN.	USPAT;	2003/11/18 11:11
			US-PGPUB;	
			EPO; JPO;	
		(114,500,000,000,000,000,000,000,000,000,00	IBM_TDB	
-	6	("4600274" "4601546" "4716403" "4728172" "4728175"	USPAT	2003/11/18 11:11
	1.5	"4761058").PN.	1100.40	2002/11/12
] -	15	4810060.URPN. ("6252248").PN.	USPAT.	2003/11/18 11:11
_	'	(0232240 J.F.IN.	USPAT; EPO; JPO;	2003/11/18 12:19
			IBM_TDB	
	15	4810060.URPN.	USPAT	2004/05/25 10:12

-	153	(TFT or (thin adj film adj transistor)) same (("W/L" or ("W" adj "L")))	USPAT;	2004/05/25 10:21
			EPO; JPO;	
			IBM_TDB	
-	71213	electroluminescen\$3 or "EL" or electro\$11uminescen\$3	USPAT;	2004/05/25 11:33
			EPO; JPO;	
1			IBM_TDB	
-	18	((TFT or (thin adj film adj transistor)) same (("W/L" or ("W" adj "L"))))	USPAT;	2004/05/25 10:25
		and (electroluminescen\$3 or "EL" or electro\$1luminescen\$3)	EPO; JPO;	
			IBM_TDB	
-	153	(TFT or (thin adj film adj transistor)) same (("W\$1L" or ("W" adj "L")))	USPAT;	2004/05/25 10:21
			EPO; JPO;	
			IBM_TDB	
-	153	(TFT or ((thin adj film) or thin\$1film) adj transistor) same (("W\$1L" or	USPAT;	2004/05/25 10:42
		("W" adj "L")))	EPO; JPO;	
			IBM_TDB	1
-	18	((TFT or ((thin adj film) or thin\$1film) adj transistor) same (("W\$1L" or	USPAT;	2004/05/25 10:42
		("W" adj "L")))) and (electroluminescen\$3 or "EL" or	EPO; JPO;	
		electro\$1luminescen\$3)	IBM_TDB	
-	2217	(TFT or ((thin adj film) or thin\$1film) adj transistor) with (size)	USPAT;	2004/05/25 11:33
			EPO; JPO;	
			IBM_TDB	
-	339	((TFT or ((thin adj film) or thin\$1film) adj transistor) with (size)) and	USPAT;	2004/05/25 10:43
		(electroluminescen\$3 or "EL" or electro\$11uminescen\$3)	EPO; JPO;	
			IBM_TDB	
-	58	((TFT or ((thin adj film) or thin\$1film) adj transistor) with (size)) same	USPAT;	2004/05/25 10:43
		(electroluminescen\$3 or "EL" or electro\$1luminescen\$3)	EPO; JPO;	
			IBM TDB	
-	29	(((TFT or ((thin adj film) or thin\$1film) adj transistor) with (size)) same	USPAT;	2004/05/25 11:35
		(electroluminescen\$3 or "EL" or electro\$11uminescen\$3)) and	EPO; JPO;	
		@ad<19991004	IBM_TDB	
-	71213	electroluminescen\$3 or "EL" or electro\$11uminescen\$3	USPĀT;	2004/05/25 11:33
1			EPO; JPO;	•
			IBM_TDB	:
-	31627	TFT or (((thin adj film) or thin\$1film) adj transistor)	USPĀT;	2004/05/25 11:34
1			EPO; JPO;	
			IBM_TDB	
-	246442	width with length	USPAT;	2004/05/25 11:35
			EPO; JPO;	
l			IBM_TDB	
-	708	(TFT or (((thin adj film) or thin\$1film) adj transistor)) with (width with	USPAT;	2004/05/25 11:35
		length)	EPO; JPO;	
			IBM TDB	
-	12	(electroluminescen\$3 or "EL" or electro\$1luminescen\$3) same ((TFT or	USPAT;	2004/05/25 11:36
		(((thin adj film) or thin\$1film) adj transistor)) with (width with length))	EPO; JPO;	
		, , , , , , , , , , , , , , , , , , ,	IBM TDB	
_	3	((electroluminescen\$3 or "EL" or electro\$1luminescen\$3) same ((TFT or	USPAT;	2004/05/25 11:36
		(((thin adj film) or thin\$1film) adj transistor)) with (width with length)))	EPO; JPO;	= 50 05. 25 11.50
	[and @ad<19991004	IBM TDB	
-	150	(electroluminescen\$3 or "EL" or electro\$11uminescen\$3) and ((TFT or	USPAT;	2004/05/25 11:36
		(((thin adj film) or thin\$1film) adj transistor)) with (width with length))	EPO; JPO;	=30 05.25 11.50
		" (" and the same of the same	IBM_TDB	
-	57	((electroluminescen\$3 or "EL" or electro\$1luminescen\$3) and ((TFT or	USPAT;	2004/05/25 11:37
		(((thin adj film) or thin\$1film) adj transistor)) with (width with length)))	EPO; JPO;	200 05,25 11.57
		and @ad<19991004	IBM TDB	
-	1	("5684365").PN.	USPAT;	2004/05/25 12:57
	1	\(\tau_{\text{-1.1.2.2.}}\)	US-PGPUB;	2004/03/23 12,37
			EPO; JPO;	
			IBM TDB	
-	10	("3807037" "3913090" "4006383" "4885432" "5073446"	USPAT	2004/05/25 12:57
		"5151629" "5276380" "5294870" "5399936" "5483082").PN.] 551711	2007/03/23 12.37
-	81	5684365.URPN.	USPAT	2004/05/25 12:57
		1	001711	2007/03/23 12.37